# Onsemi

# **Complementary Silicon Power Transistors**

# **D44H Series (NPN), D45H Series (PNP)**

These series of plastic, silicon NPN and PNP power transistors can be used as general purpose power amplification and switching such as output or driver stages in applications such as switching regulators, converters and power amplifiers.

#### Features

- Low Collector-Emitter Saturation Voltage
- Fast Switching Speeds
- Complementary Pairs Simplifies Designs
- These Devices are Pb-Free and are RoHS Compliant\*

### MAXIMUM RATINGS

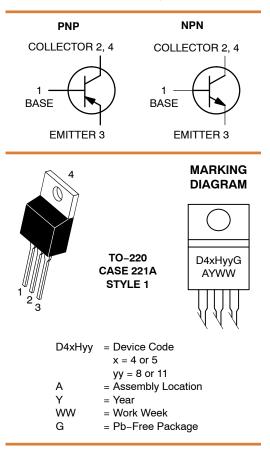
Rating	Symbol	Value	Unit
Collector-Emitter Voltage D44H8, D45H8 D44H11, D45H11	V <sub>CEO</sub>	60 80	Vdc
Emitter Base Voltage	V <sub>EB</sub>	5.0	Vdc
Collector Current – Continuous	Ι <sub>C</sub>	10	Adc
Collector Current – Peak (Note 1)	I <sub>CM</sub>	20	Adc
Total Power Dissipation @ $T_C = 25^{\circ}C$ @ $T_A = 25^{\circ}C$	PD	70 2.0	W
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. Pulse Width  $\leq$  6.0 ms, Duty Cycle  $\leq$  50%.

Purposes: 1/8" from Case for 5 Seconds

#### THERMAL CHARACTERISTICS Characteristic Symbol Unit Max Thermal Resistance, Junction-to-Case 1.8 °C/W $R_{\theta JC}$ Thermal Resistance, Junction-to-Ambient 62.5 °C/W $R_{\theta JA}$ Maximum Lead Temperature for Soldering $T_L$ 275

### **10 AMP COMPLEMENTARY** SILICON POWER **TRANSISTORS 60, 80 VOLTS**



### **ORDERING INFORMATION**

Device	Package	Shipping
D44H8G	TO-220 (Pb-Free)	50 Units/Rail
D44H11G	TO-220 (Pb-Free)	50 Units/Rail
D45H8G	TO-220 (Pb-Free)	50 Units/Rail
D45H11G	TO–220 (Pb–Free)	50 Units/Rail

\*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

°C

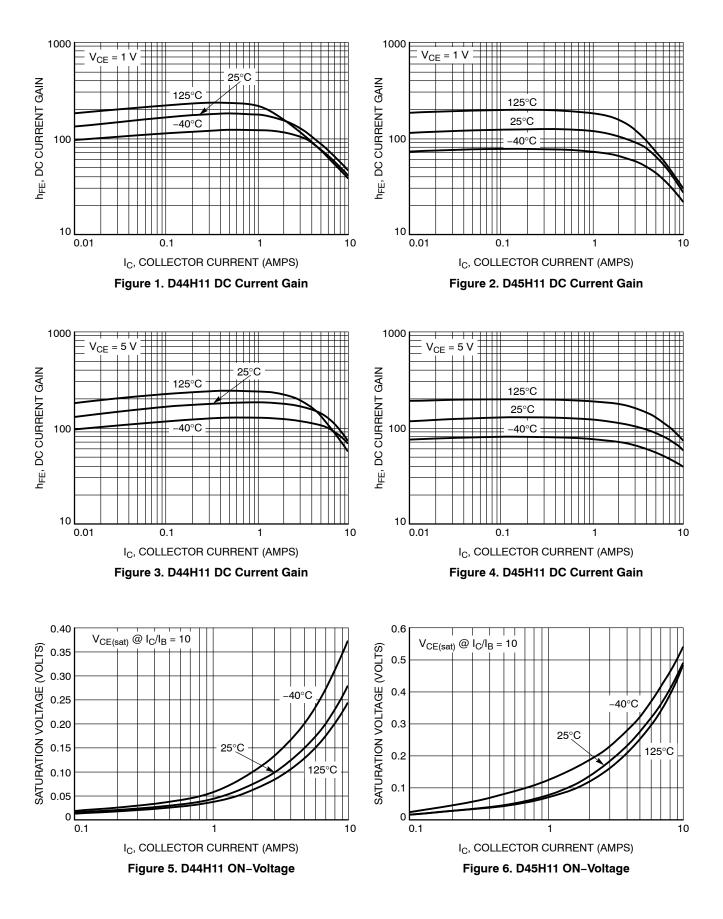
### D44H Series (NPN), D45H Series (PNP)

### **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit			
OFF CHARACTERISTICS								
Collector–Emitter Sustaining Voltage $(I_C = 30 \text{ mAdc}, I_B = 0 \text{ Adc})$	D44H8, D45H8 D44H11, D45H11	V <sub>CEO(sus)</sub>	60 80	-	-	Vdc		
Collector Cutoff Current (V <sub>CE</sub> = Rated V <sub>CEO</sub> , V <sub>BE</sub>	= 0)	I <sub>CES</sub>	-	-	10	μΑ		
Emitter Cutoff Current (V <sub>EB</sub> = 5.0 Vdc)		I <sub>EBO</sub>	-	-	10	μΑ		
ON CHARACTERISTICS								
DC Current Gain ( $V_{CE}$ = 1.0 Vdc, I <sub>C</sub> = 2.0 Adc) ( $V_{CE}$ = 1.0 Vdc, I <sub>C</sub> = 4.0 Adc)		h <sub>FE</sub>	60 40			-		
Collector–Emitter Saturation Voltage $(I_C = 8.0 \text{ Adc}, I_B = 0.4 \text{ Adc})$		V <sub>CE(sat)</sub>	-	-	1.0	Vdc		
Base-Emitter Saturation Voltage $(I_C = 8.0 \text{ Adc}, I_B = 0.8 \text{ Adc})$		V <sub>BE(sat)</sub>	-	-	1.5	Vdc		
DYNAMIC CHARACTERISTICS								
Collector Capacitance (V <sub>CB</sub> = 10 Vdc, f <sub>test</sub> = 1.0 MHz)	D44H Series D45H Series	C <sub>cb</sub>		90 160		pF		
Gain Bandwidth Product ( $I_C = 0.5$ Adc, $V_{CE} = 10$ Vdc, f = 20 MHz)	D44H Series D45H Series	fT		50 40	-	MHz		
SWITCHING TIMES								
Delay and Rise Times (I <sub>C</sub> = 5.0 Adc, I <sub>B1</sub> = 0.5 Adc)	D44H Series D45H Series	t <sub>d</sub> + t <sub>r</sub>		300 135		ns		
Storage Time ( $I_C = 5.0 \text{ Adc}, I_{B1} = I_{B2} = 0.5 \text{ Adc}$ )	D44H Series D45H Series	t <sub>s</sub>	-	500 500	-	ns		
Fall Time (I <sub>C</sub> = 5.0 Adc, I <sub>B1</sub> = 102 = 0.5 Adc)	D44H Series D45H Series	t <sub>f</sub>	-	140 100	-	ns		

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

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D44H Series (NPN), D45H Series (PNP)

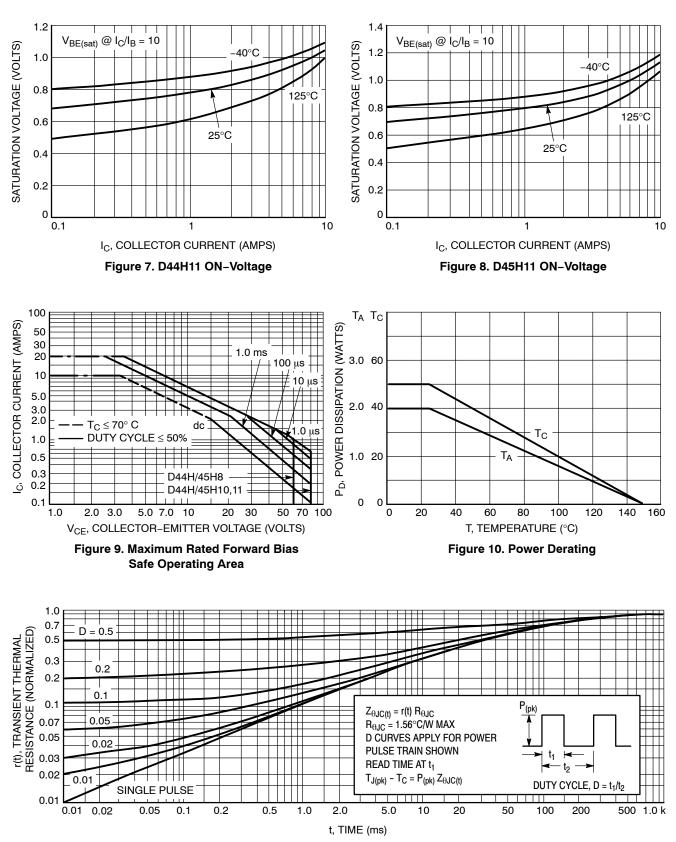
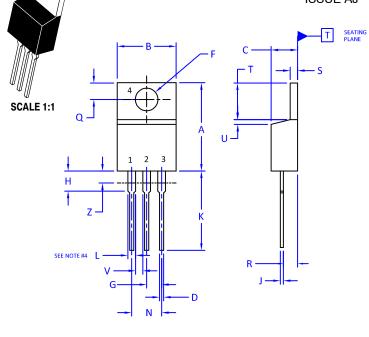


Figure 11. Thermal Response

DATE 05 NOV 2019



**TO-220** CASE 221A-09 ISSUE AJ



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 2009.

2. CONTROLLING DIMENSION: INCHES

3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

4. MAX WIDTH FOR F102 DEVICE = 1.35MM

	INCHES		MILLIME	ETERS
DIM	MIN.	MAX.	MIN.	MAX.
А	0.570	0.620	14.48	15.75
В	0.380	0.415	9.66	10.53
С	0.160	0.190	4.07	4.83
D	0.025	0.038	0.64	0.96
F	0.142	0.161	3.60	4.09
G	0.095	0.105	2.42	2.66
Н	0.110	0.161	2.80	4.10
J	0.014	0.024	0.36	0.61
К	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
Ν	0.190	0.210	4.83 5.3	
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.41
Т	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00 1.2	
V	0.045		1.15	
Z		0.080		2.04

STYLE 1: PIN 1. 2. 3. 4.	COLLECTOR EMITTER	STYLE 2: PIN 1. 2. 3. 4.	EMITTER	3.	CATHODE ANODE GATE ANODE	STYLE 4: PIN 1. 2. 3. 4.	MAIN TERMINAL 1 MAIN TERMINAL 2 GATE MAIN TERMINAL 2
STYLE 5: PIN 1. 2. 3. 4.	DRAIN SOURCE	2. 3.	ANODE CATHODE ANODE CATHODE	2. 3.	CATHODE ANODE CATHODE ANODE	STYLE 8: PIN 1. 2. 3. 4.	••••••
STYLE 9: PIN 1. 2. 3. 4.	COLLECTOR EMITTER	STYLE 10: PIN 1. 2. 3. 4.	GATE SOURCE DRAIN	STYLE 11: PIN 1. 2. 3. 4.	DRAIN SOURCE GATE	STYLE 12 PIN 1. 2. 3. 4.	MAIN TERMINAL 1 MAIN TERMINAL 2 GATE NOT CONNECTED

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